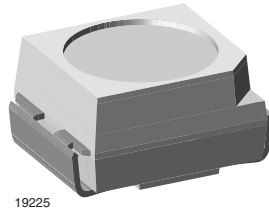


## Power SMD LED in PLCC-2 Package



19225

### DESCRIPTION

The VLMK33.. series is an advanced modification of the Vishay VLMK33.. series. It is designed to incorporate larger chips, therefore, capable of withstanding a 50 mA drive current.

The package of the VLMK33.. is the PLCC-2 (equivalent to a size B tantalum capacitor).

It consists of a lead frame which is embedded in a white thermoplast. The reflector inside this package is filled up with clear epoxy.

### PRODUCT GROUP AND PACKAGE DATA

- Product group: LED
- Package: SMD PLCC-2
- Product series: power
- Angle of half intensity:  $\pm 60^\circ$

### FEATURES

- Available in 8 mm tape
- ESD-withstand voltage: up to 2 kV according to JESD22-A114-B
- Compatible with IR reflow, vapor phase and wave solder processes according to CECC 00802 and J-STD-020C
- Preconditioning: acc. to JEDEC level 2a
- Automotive qualified
- Lead (Pb)-free device
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



### APPLICATIONS

- Interior and exterior lighting
- Indicator and backlighting purposes for audio, video, LCDs, switches, symbols, illuminated advertising etc.
- Illumination purpose, alternative to incandescent lamps
- Automotive qualified
- General use

### PARTS TABLE

PART	COLOR, LUMINOUS INTENSITY	TECHNOLOGY
VLMK33Q2T1-GS08	Red, $I_V > (90 \text{ to } 355) \text{ mcd}$	AllnGaP on GaAs
VLMK33Q2T1-GS18	Red, $I_V > (90 \text{ to } 355) \text{ mcd}$	AllnGaP on GaAs
VLMK33R1S2-GS08	Red, $I_V = (112 \text{ to } 280) \text{ mcd}$	AllnGaP on GaAs
VLMK33R1S2-GS18	Red, $I_V = (112 \text{ to } 280) \text{ mcd}$	AllnGaP on GaAs
VLMK33S1T1-GS08	Red, $I_V = (180 \text{ to } 355) \text{ mcd}$	AllnGaP on GaAs
VLMK33S1T1-GS18	Red, $I_V = (180 \text{ to } 355) \text{ mcd}$	AllnGaP on GaAs

ABSOLUTE MAXIMUM RATINGS <sup>1)</sup> VLMK33..				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage <sup>2)</sup>		$V_R$	5	V
DC Forward current		$I_F$	50	mA
Power dissipation		$P_V$	130	mW
Junction temperature		$T_j$	125	°C
Operating temperature range		$T_{amb}$	- 40 to + 100	°C
Storage temperature range		$T_{stg}$	- 40 to + 100	°C
Soldering temperature	$t \leq 5$ s	$T_{sd}$	260	°C
Thermal resistance junction/ambient	mounted on PC board (pad size > 16 mm <sup>2</sup> )	$R_{thJA}$	400	K/W

Note:

1)  $T_{amb} = 25$  °C unless otherwise specified

2) Driving LED in reverse direction is suitable for a short term application

OPTICAL AND ELECTRICAL CHARACTERISTICS <sup>1)</sup> VLMK33.., RED							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN	TYP.	MAX	UNIT
Luminous intensity	$I_F = 20$ mA	VLMK33Q2T1	$I_V$	90		355	mcd
		VLMK33R1S2	$I_V$	112		280	mcd
		VLMK33S1T1	$I_V$	180		355	mcd
Luminous flux/Luminous intensity			$\phi_V/I_V$		3.14		mlm/mcd
Dominant wavelength	$I_F = 20$ mA		$\lambda_d$	611	617	624	nm
Peak wavelength	$I_F = 20$ mA		$\lambda_p$		624		nm
Spectral bandwidth at 50 % $I_{rel\ max}$	$I_F = 20$ mA		$\Delta\lambda$		18		nm
Angle of half intensity	$I_F = 20$ mA		$\phi$		± 60		deg
Forward voltage	$I_F = 20$ mA		$V_F$		1.9	2.5	V
Reverse current	$V_R = 5$ V		$V_R$		0.01	10	µA

Note:

1)  $T_{amb} = 25$  °C unless otherwise specified

LUMINOUS INTENSITY CLASSIFICATION		
GROUP	LUMINOUS INTENSITY (MCD)	
	MIN	MAX
Q1	71	90
Q2	90	112
R1	112	140
R2	140	180
S1	180	224
S2	224	280
T1	280	355
T2	355	450

Note:

Luminous intensity is tested at a current pulse duration of 25 ms and an accuracy of ± 11 %.

The above type Numbers represent the order groups which include only a few brightness groups. Only one group will be shipped on each reel (there will be no mixing of two groups on each reel). In order to ensure availability, single brightness groups will be not orderable. In a similar manner for colors where wavelength groups are measured and binned, single wavelength groups will be shipped on any one reel. In order to ensure availability, single wavelength groups will be not orderable.

COLOR CLASSIFICATION		
GROUP	DOMINANT WAVELENGTH (NM)	
	RED	
	MIN	MAX
1	611	618
2	614	622
3		
4		
5		
6		

Note:

Wavelength are tested at a current pulse duration of 25 ms and an accuracy of ± 1 nm

CROSSING TABLE	
VISHAY	OSRAM
VLMK33Q2T1	LAT676-Q2T1
VLMK33R1S2	LAT676-R1S2
VLMK33S1T1	LAT676-S1T1

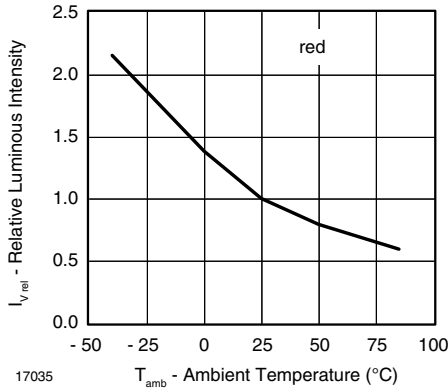


Figure 7. Relative Luminous Intensity vs. Amb. Temperature

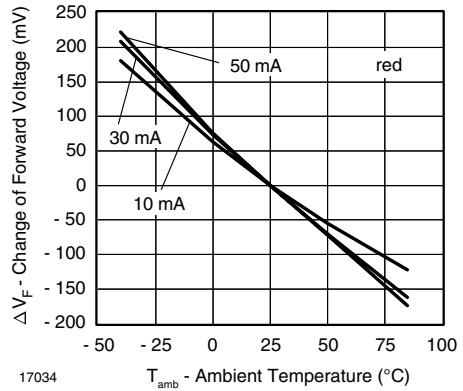


Figure 9. Change of Forward Voltage vs. Ambient Temperature

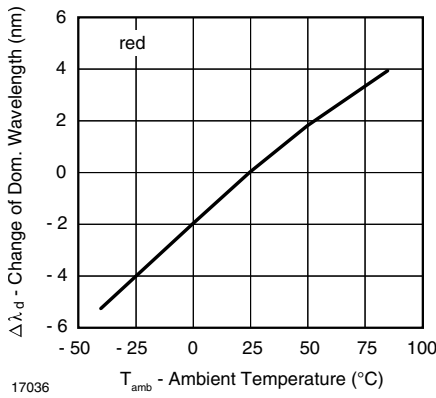
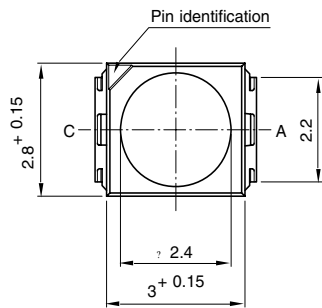
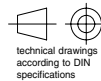
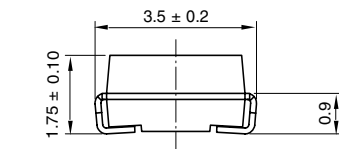
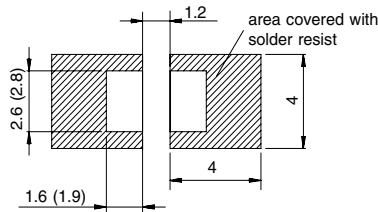


Figure 8. Change of Dominant Wavelength vs. Ambient Temperature

**PACKAGE DIMENSIONS** in millimeters



**Mounting Pad Layout**



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